#### Photocouplers GaAlAs Infrared LED & Photo IC

## **TLP5214**

## Isolated IGBT/Power MOSFET gate drive AC and brushless DC motor drives

Industrial Inverters and Uninterruptible Power Supply (UPS)

The TLP5214 is a highly integrated 4.0A output current IGBT gate drive photocoupler housed in a long creepage and clearance SO16L package.

The TLP5214, a smart gate driver photocoupler, includes functions of IGBT desaturation detection, isolated fault status feedback, soft IGBT turn-off, active Miller cramping and under voltage lockout (UVLO).

This photocoupler is suitable for driving IGBT and power MOSFET used in inverter applications.

The TLP5214 consists two GaAlAs infrared light-emitting diodes (LEDs) and two high-gain and high-speed ICs. They realize high current, high-speed output control and output fault status feedback.

Peak output current: ±4.0 A (max) Guaranteed performance over temperature: -40°C to 110°C Supply current: 3.5 mA (max) Power supply voltage: 15 V to 30 V Threshold input current:  $I_{FLH} = 6 \text{ mA (max)}$ Switching time (tplh / tphl): 150 ns (max) Common mode transient immunity:  $\pm 35 \text{ kV/}\mu\text{s} \text{ (min)}$ 5000 Vrms (min) Isolation voltage:

UL approved: UL1577, File No.E67349

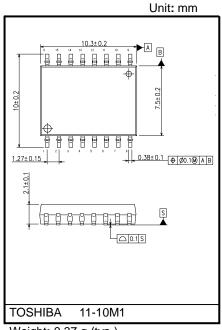
c-UL approved :CSA Component Acceptance Service No. 5A, File No.E67349

Option (D4) VDE approved : DIN EN60747-5-5(Note)

EN60065 or EN60950-1,

EN62368-1

CQC-approved: GB4943.1, GB8898 Japan Factory



Weight: 0.37 g (typ.)

#### Construction mechanical rating

|                      | SO16L        |
|----------------------|--------------|
| Height               | 2.3 mm (max) |
| Creepage Distance    | 8.0 mm (min) |
| Clearance            | 8.0 mm (min) |
| Insulation Thickness | 0.4 mm (min) |

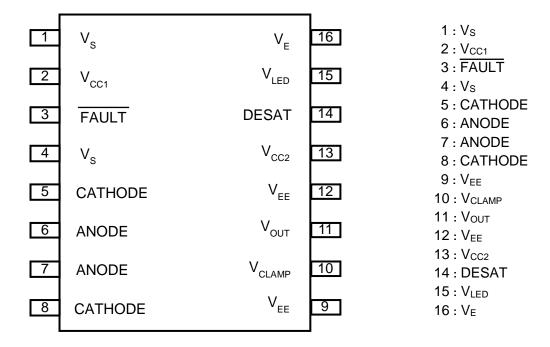
Note: When a EN60747-5-5 approved type is needed, please designate "Option(D4)"

#### **Truth Table**

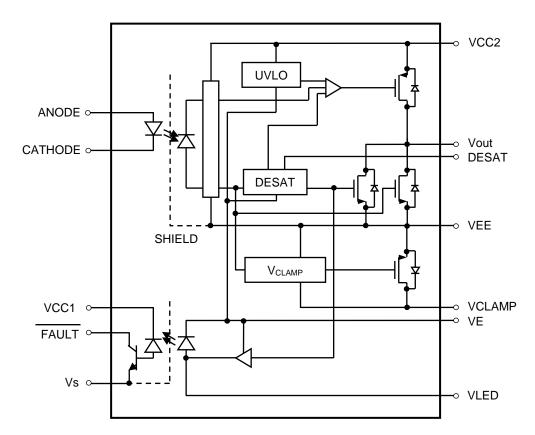
| l <sub>F</sub> | UVLO  | DESAT                           | FAULT                        | V              |  |
|----------------|---|---------------------------------|------------------------------|----------------|--|
| IF             | (V <sub>CC2</sub> -V <sub>E</sub> )             | (14Pin DESAT Terminal Input)    | (3Pin FAULT Terminal Output) | V <sub>o</sub> |  |
| OFF            | Not Active ( > V <sub>UVLO</sub> <sup>+</sup> ) | Not Active                      | High                         | Low            |  |
| ON             | Not Active ( > V <sub>UVLO</sub> <sup>+</sup> ) | Low ( < V <sub>DESATth</sub> )  | High                         | High           |  |
| ON             | Not Active ( > V <sub>UVLO</sub> <sup>+</sup> ) | High ( > V <sub>DESATth</sub> ) | Low ( FAULT)                 | Low            |  |
| ON             | Active ( < V <sub>UVLO</sub> -)                 | Not Active                      | High                         | Low            |  |
| OFF            | Active ( < V <sub>UVLO</sub> -)                 | Not Active                      | High                         | Low            |  |

Start of commercial production

## Pin Configuration (top view)



#### **Internal Circuit**



Note: A 1-μF bypass capacitor must be connected between pins 9 and 13, pins 13 and 16.

#### Absolute Maximum Ratings (Note) (Ta = 25°C ,Unless otherwise specified)

|          | Characteristic                         | Symbol                | Rating                               | Unit  |       |
|----------|--|-----------------------|--------------------------------------|---|-------|
| LED      | Input forward current                  | lF                    | 25                                   | mA  |       |
|          | Input forward current derating (Ta ≥   | 95°C)                 | ΔΙϝ/ΔΤα                              | -1  | mA/°C |
|          | Peak transient input forward current   | (Note 1)              | I <sub>FPT</sub>                     | 1   | Α     |
|          | Peak transient input forward current d | derating (Ta ≥ 95°C)  | ΔΙϝρτ/ΔΤα                            | -25   | mA/°C |
|          | Reverse Input Voltage                  |                       | $V_R$                                | 6   | V     |
|          | Input power dissipation                |                       | PD                                   | 145   | mW    |
|          | Input power dissipation derating (Ta   | ı ≥ 95°C)             | Δ P <sub>D</sub> /ΔTa                | -5.0  | mW/°C |
| Detector | Positive Input Supply Voltage          |                       | V <sub>CC1</sub>                     | −0.5 to 7                                       | V     |
|          | "H" peak output current                | Ta = -40 to 110 °C    | Іорн                                 | -4.0  | А     |
|          | "L" peak output current                | (Note 2)              | IOPL                                 | +4.0  | А     |
|          | FAULT Output Current                   |                       | IFAULT                               | 8   | mA    |
|          | FAULT Pin Voltage                      |                       | V <sub>FAULT</sub>                   | −0.5 to V <sub>CC1</sub>                        | V     |
|          | Total Output Supply Voltage            |                       | (V <sub>CC2</sub> -V <sub>EE</sub> ) | −0.5 to 35                                      | V     |
|          | Negative Output Supply Voltage         |                       | (V <sub>E</sub> -V <sub>EE</sub> )   | -0.5 to 15                                      | V     |
|          | Positive Output Supply Voltage         |                       | (V <sub>CC2</sub> -V <sub>E</sub> )  | -0.5 to 35 - (V <sub>E</sub> -V <sub>EE</sub> ) | V     |
|          | Output voltage                         |                       | Vo                                   | −0.5 to V <sub>CC2</sub>                        | V     |
|          | Peak Clamping Sinking Current          |                       | I <sub>Clamp</sub>                   | 1.7   | А     |
|          | Miller Clamping Pin Voltage            |                       | $V_{Clamp}$                          | −0.5 to V <sub>CC2</sub>                        | V     |
|          | DESAT Voltage                          |                       | $V_{DESAT}$                          | $V_E$ to $V_E + 10$                             | V     |
|          | Output power dissipation               |                       | Po                                   | 410   | mW    |
|          | Output power dissipation (Ta ≥ 95°C    | Δ P <sub>O</sub> /ΔTa | -14.0                                | mW/°C   |       |
| Common   | Operating temperature range            | Topr                  | -40 to 110                           | °C  |       |
|          | Storage temperature range              | Tstg                  | −55 to 125                           | °C  |       |
|          | Lead soldering temperature (10 s)      | (Note 3)              | Tsol                                 | 260   | °C    |
|          | Isolation voltage (AC, 60 s, R.H. ≤ 60 | %) (Note 4)           | BVs                                  | 5000  | Vrms  |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: A ceramic capacitor (1  $\mu$ F) should be connected between pins 9 and 13, pins 13 and 16 to stabilize the operation of the high gain linear amplifier. Furthermore, in case  $V_E$ - $V_{EE}$  > 0 V, a bypass capacitor, which has good high frequency characteristic, a ceramic capacitor (1  $\mu$ F) should be connected between pins 9 and 16. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

- Note 1: Pulse width  $P_W \le 1 \mu s$ , 300 pps
- Note 2: Exponential waveform pulse width  $P_W \le 0.2~\mu s, f \le 15~kHz, V_{CC} = 15~V$
- Note 3: For the effective lead soldering area.
- Note 4: This device considered a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.



#### **Recommended Operating Conditions (Note)**

| Characteristics                      | Symbol                              | Min | Тур. | Max                                     | Unit |
|--------------------------------------|-------------------------------------|-----|------|---|------|
| Total Output Supply Voltage (Note 5) | $(V_{CC2}-V_{EE})$                  | 15  | =    | 30                                      | V    |
| Negative Output Supply Voltage       | (V <sub>E</sub> -V <sub>EE</sub> )  | 0   | =    | 15                                      | V    |
| Positive Output Supply Voltage       | (V <sub>CC2</sub> -V <sub>E</sub> ) | 15  | =    | 30 - (V <sub>E</sub> -V <sub>EE</sub> ) | V    |
| Input On-State Current (Note 6)      | I <sub>F(ON)</sub>                  | 7.5 | =    | 12                                      | mA   |
| Input Off-State Voltage              | $V_{F(OFF)}$                        | 0   | =    | 0.8                                     | V    |
| Operating frequency (Note 7)         | f                                   | -   | -    | 50                                      | kHz  |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 5: If the Vcc rise slope is sharp, an internal circuit might not operate with stability. Please design the Vcc rise slope under 3.0 V /  $\mu$ s.

Note 6: Input signal rise time (fall time)  $\leq$  0.5  $\mu$ s.

Note 7: Exponential waveform.  $I_{OPH} \ge -4.0 \text{ A} (\le 90 \text{ ns}), I_{OPL} \le 4.0 \text{ A} (\le 90 \text{ ns}), Ta = 110^{\circ}\text{C}$ 

#### Electrical Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

| Characteristics                      | Symbol              | Test<br>Circuit | Test Condition   | Min                   | Тур.*                 | Max   | Unit |
|--------------------------------------|---------------------|-----------------|--|-----------------------|-----------------------|-------|------|
| Input Forward Voltage                | $V_{F}$             | 1               | I <sub>F</sub> = 10 mA, Ta = 25°C                                | 1.4                   | -                     | 1.7   | V    |
| Input Reverse Current                | I <sub>R</sub>      | _               | V <sub>R</sub> = 5 V   | -                     | -                     | 10    | μΑ   |
| Input Capacitance                    | Ct                  | _               | V=0 V, f=1 MHz, Ta = 25°C  | -                     | 95                    | -     | pF   |
| FAULT Low Level Output Voltage       | V=                  |                 | IFAULT = 1.1 mA, V <sub>CC</sub> 1=5.5 V                         | -                     | 0.2                   | 0.4   | V    |
| PAOLT Low Level Output Voltage       | VFAULTL             |                 | I <sub>FAULT</sub> = 1.1 mA, V <sub>CC</sub> 1=3.3 V             | -                     | 0.2                   | 0.4   | ]    |
| FAULT High Level Output Current      | leau eu             |                 | V <sub>FAULT</sub> = 5.5 V, V <sub>CC</sub> 1 = 5.5 V, Ta = 25°C | -                     | -                     | 0.5   |      |
| PAOLT High Level Output Current      | IFAULTH             |                 | V <sub>FAULT</sub> = 5.5 V, V <sub>CC</sub> 1 = 3.3 V, Ta = 25°C | -                     | -                     | 0.3   | μА   |
| High Level Output Current (Note 8)   | _                   | 1               | Vo = Vcc2 - 4 V  | =                     | -4.0                  | -1.2  |      |
| rigii Level Output Current (Note 8)  | I <sub>OPH</sub>    | I               | $V_0 = V_{CC}2 - 7 V$  | -                     | -6.5                  | -3.0  | _    |
| Low Level Output Current (Note 8)    | -                   | 2               | $V_O = V_{EE} + 2.5 \text{ V}$                                   | 1.2                   | 3.5                   | =     | A    |
| Low Level Output Current (Note 6)    | I <sub>OPL</sub>    | 2               | $V_0 = V_{EE} + 7 V$   | 3                     | 5.5                   | -     |      |
| Low Level Output Current             | _                   |                 | V <sub>O</sub> - V <sub>FF</sub> = 14 V                          | 90                    | 150                   | 230   | A    |
| During Fault Condition               | I <sub>OLF</sub>    | -               | V <sub>O</sub> - V <sub>EE</sub> = 14 V                          | 90                    | 150                   | 230   | mA   |
| High Level Output Voltage            | $V_{OH}$            | 3               | I <sub>O</sub> = −100 mA   | V <sub>CC</sub> 2-0.3 | V <sub>CC</sub> 2-0.2 | =     |      |
| Low Level Output Voltage             | $V_{OL}$            | 4               | I <sub>O</sub> = 100 mA  | -                     | 0.1                   | 0.2   | ٧    |
| Clamp Pin Threshold Voltage          | $V_{tClamp}$        | _               | _  | -                     | 3.0                   | =     |      |
| Clamp Low Level Sinking Current      | I <sub>CL</sub>     | _               | $V_O = V_{EE} + 2.5 \text{ V}$                                   | 0.56                  | 1.8                   | =     | Α    |
| High Level Supply Current            | I <sub>CC2H</sub>   | 5               | I <sub>O</sub> = 0 mA  | -                     | 2.4                   | 3.5   |      |
| Low Level Supply Current             | I <sub>CC2L</sub>   | 6               | I <sub>O</sub> = 0 mA  | -                     | 2.3                   | 3.5   | ^    |
| Blanking Capacitor Charging Current  | I <sub>CHG</sub>    | 7               | V <sub>DESAT</sub> = 2 V   | -0.13                 | -0.24                 | -0.33 | mA   |
| Blanking Capacitor Discharge Current | I <sub>DSCHG</sub>  | 8               | V <sub>DESAT</sub> = 7 V   | 10                    | 49                    | -     |      |
| DESAT Threshold Voltage              | V <sub>DESAT</sub>  | _               | Vcc2-V <sub>E</sub> >V <sub>UVLO-</sub>                          | 6                     | 6.5                   | 7.5   |      |
| LIVI O Throshold Voltage             | $V_{UVLO}^+$        | 9               | V <sub>0</sub> >5 V  | 10.5                  | 11.6                  | 13.5  | V    |
| UVLO Threshold Voltage               | V <sub>UVLO</sub> - | 9               | V <sub>0</sub> <5 V  | 9.2                   | 10.3                  | 11.1  | V    |
| UVLO hysteresis                      | UVLO <sub>HYS</sub> | -               | _  | -                     | 1.3                   | -     |      |

(\*): All typical values are at Ta = 25°C Note 8: lo application time  $\leq 50 \mu s$ , 1 pulse



#### Electrical Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

| Characteristics               | Symbol | Test<br>Circuit | Test Condition       | Min | Тур.* | Max | Unit |
|-------------------------------|--------|-----------------|----------------------|-----|-------|-----|------|
| Threshold Input Current(L/H)  | IFLH   | 10              | Vcc = 30 V, Vo < 5 V | -   | 0.8   | 6   | mA   |
| Threshold Input Voltage (H/L) | VFHL   |                 | Vcc = 30 V, Vo > 5 V | 0.8 | =     | -   | V    |

<sup>(\*):</sup> All typical values are at Ta = 25°C

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design.

It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

#### Isolation Characteristics (Note) (Ta = 25 °C)

| Characteristic              | Symbol | Test Condition                      | Min                | Тур.             | Max | Unit      |  |
|-----------------------------|--------|-------------------------------------|--------------------|------------------|-----|-----------|--|
| Capacitance input to output | Cs     | Vs = 0 V, f = 1 MHz                 | -                  | 1.0              | -   | pF        |  |
| Isolation resistance        | Rs     | R.H. ≤ 60 %, V <sub>S</sub> = 500 V | 1×10 <sup>12</sup> | 10 <sup>14</sup> | -   | Ω         |  |
|                             |        | AC, 60 s                            | 5000               | -                | -   | \/ r.m. o |  |
| Isolation voltage           | BVs    | AC, 1 s, in oil                     | =                  | 10000            | -   | Vrms      |  |
|                             |        | DC, 60 s, in oil                    | -                  | 10000            | -   | Vdc       |  |

Note: This device considered a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

#### Switching Characteristics (Note) (Ta = -40 to 110 °C, unless otherwise specified)

| Characteristics                               |                       | Symbol                    | Test<br>Circuit | Test Condition   |   | Min | Тур.*                                   | Max | Unit  |    |  |
|---|-----------------------|---------------------------|-----------------|--|---|-----|---|-----|-------|----|--|
| Propagation delay time                        | $L \to H$             | tpLH                      |                 |  | $I_F = 0 \rightarrow 10 \text{ mA}$                   | 50  | 85                                      | 150 |       |    |  |
| (Note 9)                                      | $H \rightarrow L$     | tpHL                      |                 | ) / 00 \ /   | $IF = 10 \rightarrow 0 \text{ mA}$                    | 50  | 90                                      | 150 |       |    |  |
| Output rise time (10-90 %                     | ) (Note 9)            | tr                        |                 | $V_{CC2} = 30 \text{ V}$ $R_g = 10 \Omega$   | $IF = 0 \rightarrow 10 \text{ mA}$                    | -   | 32                                      | -   |       |    |  |
| Output fall time (90-10 %)                    | (Note 9)              | tf                        | 11              | C <sub>g</sub> = 25 nF   | $I_F = 10 \rightarrow 0 \text{ mA}$                   | -   | 18                                      | -   | ns    |    |  |
| Pulse with distortion                         | (Note 9)              | tpHL-tpLH                 |                 | Duty = 50%   | I <sub>F</sub> = 0 ↔ 10 mA                            | 1   | -                                       | 50  |       |    |  |
| Propagation delay skew (device to device)     | (Note 9)<br>(Note 10) | tpsk                      |                 |  |   |     | $I_F = 0 \leftrightarrow 10 \text{ mA}$ | -80 | -     | 80 |  |
| DESAT Sense to 90% Del                        | ay                    | t <sub>DESAT(90%)</sub>   |                 | $C_{DESAT}$ = 100 pF, Rg = 10 $\Omega$<br>$Cg$ = 25 nF, $V_{CC2}$ = 30 V<br>$R_F$ = 2.1 k $\Omega$ |   | =   | 180                                     | 500 |       |    |  |
| DESAT Sense to 10% Del                        | ay                    | t <sub>DESAT(10%)</sub>   |                 |  |   | =   | 3.5                                     | 5   | μS    |    |  |
| DESAT Sense to Low Leve<br>FAULT Signal Delay | el                    | t <sub>DESAT(FAULT)</sub> | 40              | C <sub>DESAT</sub> = 100 pl  | _   | -   | 300                                     | 500 |       |    |  |
| DESAT Sense to Low Prop<br>Delay              | oagation              | t <sub>DESAT(LOW)</sub>   | 12              | $Cg = 25 \text{ nF}, V_{C}$ $R_{F} = 2.1 \text{ k}\Omega$  | CC2 = 30 V  | -   | 200                                     | -   | ns    |    |  |
| DESAT Input Mute                              |                       | t <sub>DESAT(MUTE)</sub>  |                 | C <sub>F</sub> = Open  |   | 7   | 14                                      | -   |       |    |  |
| RESET to High Level FAU Signal Delay          | LT                    | treset(fault)             |                 |  | VCC1 = 5.5 V  | 0.2 | 0.45                                    | 2   | μS    |    |  |
| Common Mode Transient lat High Level Output   | Immunity              | СМн                       | 13 to           |  | I <sub>F</sub> = 10 mA<br>V <sub>O (min)</sub> = 26 V | ±35 | -                                       | -   | k\//a |    |  |
| Common Mode Transient lat Low Level Output    | Immunity              | CML                       | 16              |  | I <sub>F</sub> = 0 mA<br>V <sub>O (max)</sub> = 1 V   | ±35 | -                                       |     | kV/μs |    |  |

<sup>(\*):</sup> All typical values are at Ta = 25 °C.

Note 9: Input signal (f = 10 kHz, duty = 50%, tr = tf = 5 ns or less)

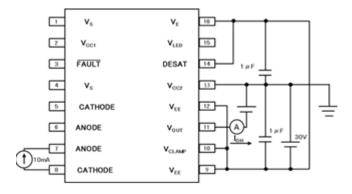
CL is approximately 15 pF which includes probe and stray wiring capacitance.

Note 10: The propagation delay skew, tpsk, is equal to the magnitude of the worst-case difference in tpHL and/or tpLH that will be seen between units at the same given conditions (supply voltage, input current, temperature, etc).

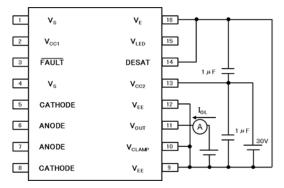
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#### **Test Circuit**

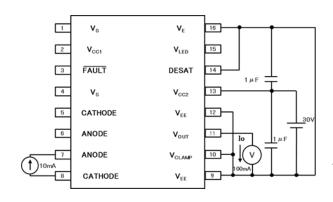
Test Circuit 1: IOPH



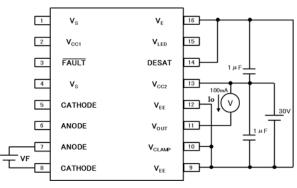
**Test Circuit 2: IOPL** 



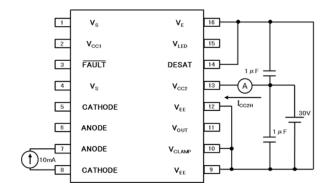
**Test Circuit 3: Voh** 



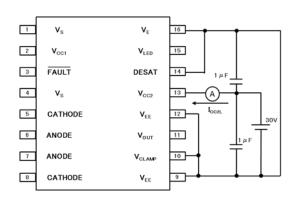
**Test Circuit 4: Vol** 



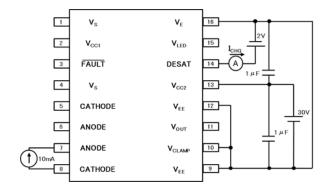
Test Circuit 5: ICC2H



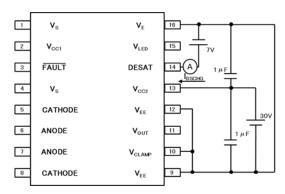
Test Circuit 6: ICC2L



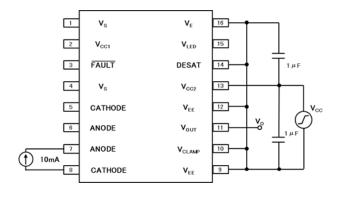
**Test Circuit 7: ICHG** 



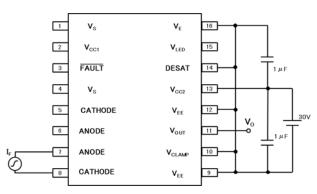
**Test Circuit 8: IDSCHG** 



**Test Circuit 9: VUVLO** 

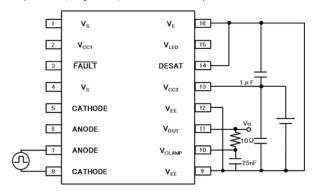


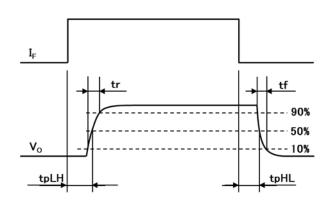
Test Circuit 10: IFLH



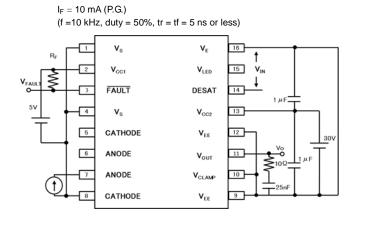
Test Circuit 11: tpLH, tpHL, tr, tf, | tpHL-tpLH |

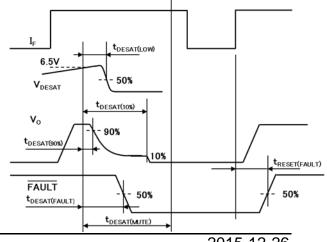






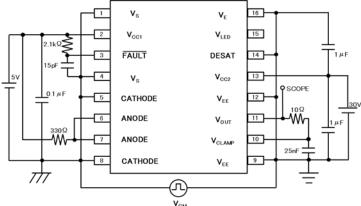
Test Circuit 12: tdesat(90%), tdesat(10%), tdesat(fault), tdesat(Low), tdesat(Mute), treset(fault)



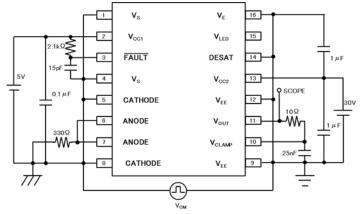


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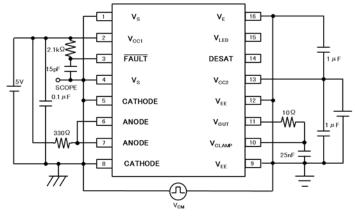
#### Test Circuit 13: CMR LED1 ON



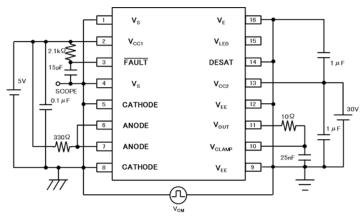
Test Circuit 14: CMR\_LED1 OFF



Test Circuit 15: CMR\_LED2 ON

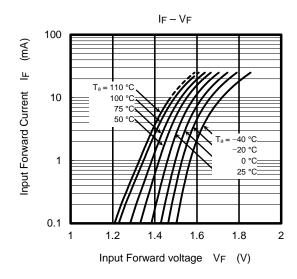


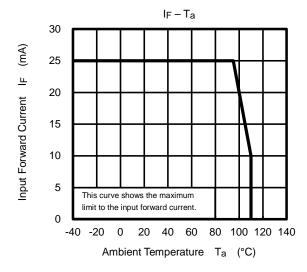
Test Circuit 16: CMR\_LED2 OFF

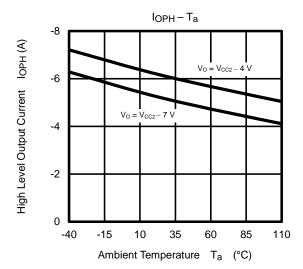


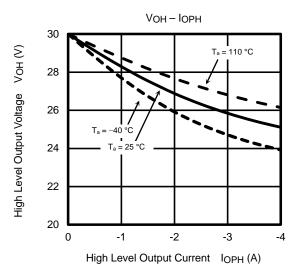
 $\mathsf{CML}$  (CMH) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

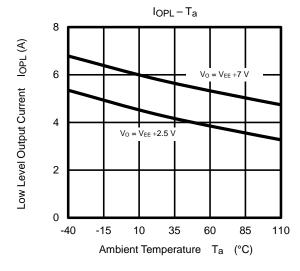
#### **Characteristics Curve**

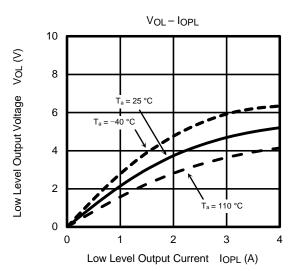


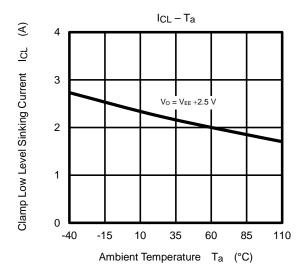


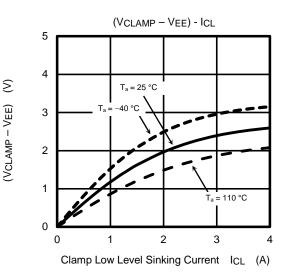


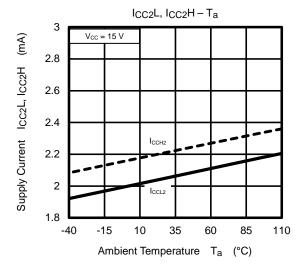


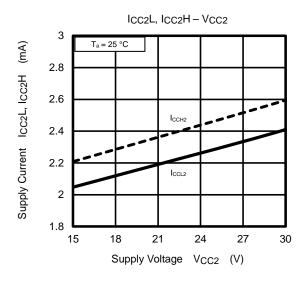


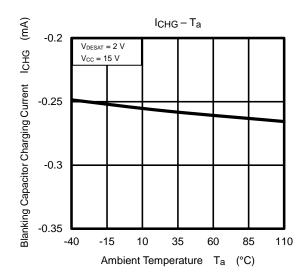


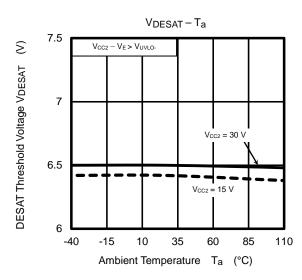


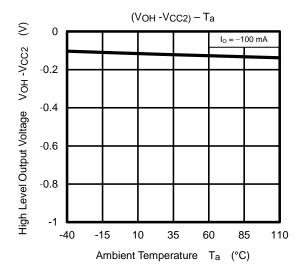


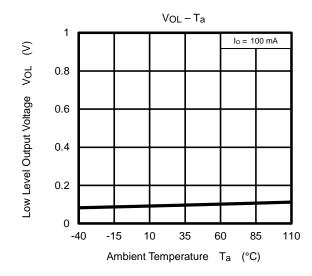


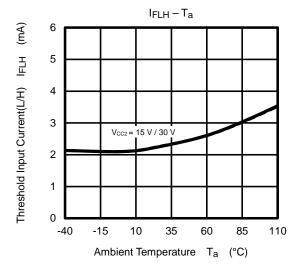


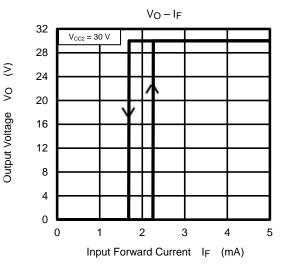


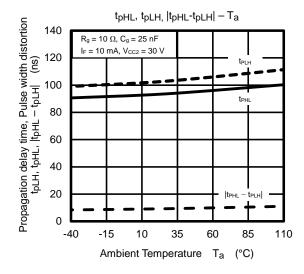


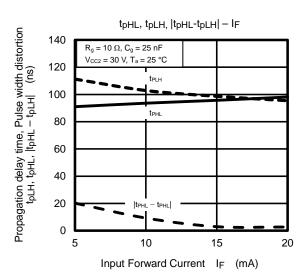


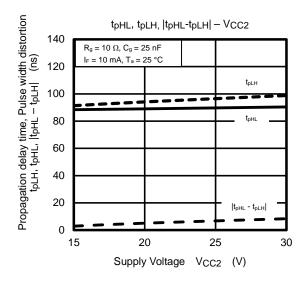


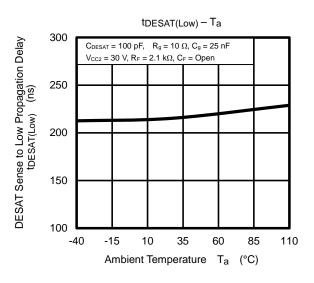


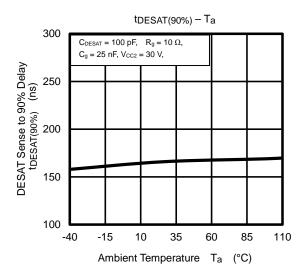


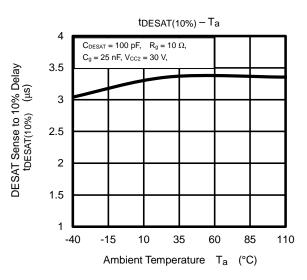


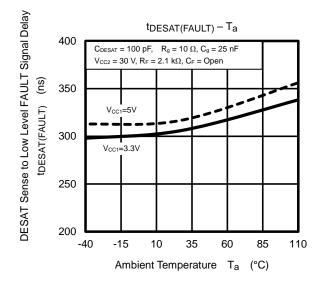


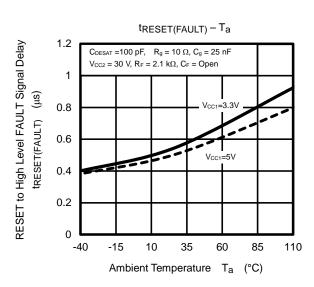












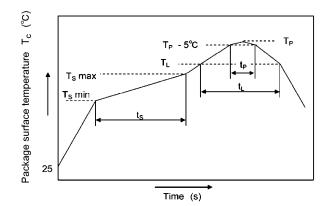
## PRECAUTIONS OF SURFACE MOUNTING TYPE PHOTOCOUPLER SOLDERING & GENERAL STORAGE

#### (1) Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

#### 1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is use



|  | Symbol         | Min | Max | Unit |
|--|----------------|-----|-----|------|
| Preheat temperature  | Ts             | 150 | 200 | °C   |
| Preheat time   | ts             | 60  | 120 | S    |
| Ramp-up rate (T <sub>L</sub> to T <sub>P</sub> )           |                |     | 3   | °C/s |
| Liquidus temperature                                       | T∟             | 217 |     | °C   |
| Time above T <sub>L</sub>                                  | tL             | 60  | 150 | S    |
| Peak temperature   | T <sub>P</sub> |     | 260 | ŷ    |
| Time during which $T_c$ is between ( $T_P - 5$ ) and $T_P$ | t <sub>P</sub> |     | 30  | s    |
| Ramp-down rate $(T_P \text{ to } T_L)$                     |                |     | 6   | °C/s |

### An Example of a Temperature Profile When Lead(Pb)-Free Solder Is Used

- Reflow soldering must be performed once or twice.
- The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

#### 2) When using soldering Flow

- Apply preheating of 150 °C for 60 to 120 seconds.
- Mounting condition of 260 °C or less within 10 seconds is recommended.
- Flow soldering must be performed once

#### 3) When using soldering Iron

- Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C.
  - Heating by soldering iron must be only once per 1 lead



#### (2) Precautions for General Storage

- 1) Do not store devices at any place where they will be exposed to moisture or direct sunlight.
- 2) When transportation or storage of devices, follow the cautions indicated on the carton box.
- 3) The storage area temperature should be kept within a temperature range of 5 degree C to 35 degree C, and relative humidity should be maintained at between 45% and 75%.
- 4) Do not store devices in the presence of harmful (especially corrosive)gases, or in dusty conditions.
- 5) Use storage areas where there is minimal temperature fluctuation. Because rapid temperature changes can cause condensation to occur on stored devices, resulting in lead oxidation or corrosion, as a result, the solderability of the leads will be degraded.
- 6) When repacking devices, use anti-static containers.
- 7) Do not apply any external force or load directly to devices while they are in storage.
- 8) If devices have been stored for more than two years, even though the above conditions have been followed, it is recommended that solderability of them should be tested before they are used.

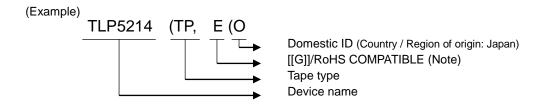
# Specifications for Embossed-Tape Packing (TP) for SO16L Coupler

#### 1. Applicable Package

| Package | Product Type          |  |  |
|---------|-----------------------|--|--|
| SO16L   | Long creepage Coupler |  |  |

#### 2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.



Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

#### 3. Tape Dimensions

#### 3.1 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 1.

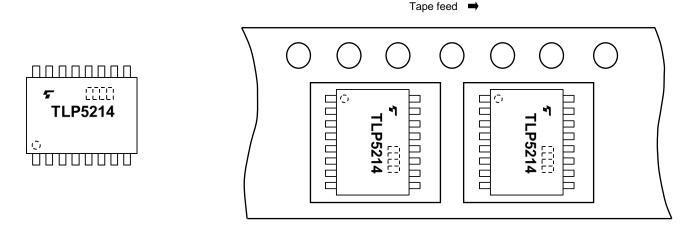


Figure 1 Device Orientation

#### 3.2 Packing Quantity: 1500 per reel

#### 3.3 Empty Device Recesses Are as Shown in Table 1.

| Table1 | Empty | Device | Recesses |
|--------|-------|--------|----------|
| iabiei |       | Device | Recesses |

|   | Standard                | Remarks  |  |
|---|-------------------------|--|--|
| Occurrences of 2 or more successive empty device recesses | 0 device                | Within any given 40-mm section of tape, not including leader and trailer |  |
| Single empty device recesses                              | 6 device (max) per reel | Not including leader and trailer   |  |

#### 3.4 Start and End of Tape

The start of the tape has 14 or more empty holes. The end of the tape has 34 or more empty holes and more than 30mm only for a cover tape.

#### 3.5 Tape Specification

- (1) Material: Plastic (for protection against static electricity)
- (2) Dimensions: The tape dimensions are shown in Figure 2 and Table 2.

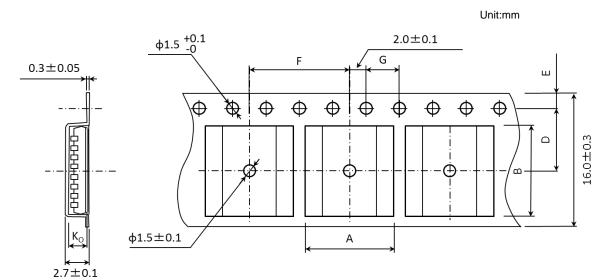


Figure 2 Tape Forms

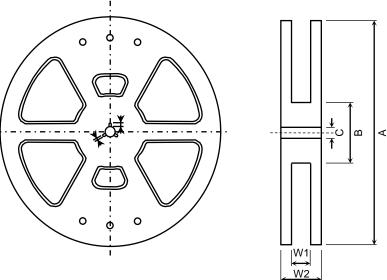
**Table 2 Tape Dimensions** 

Unit: mm Unless otherwise specified: ±0.1

| Symbol         | Dimension | Remark  |
|----------------|-----------|---|
| А              | 10.4      | _   |
| В              | 10.7      | _   |
| D              | 7.5       | Center line of indented square hole and sprocket hole |
| E              | 1.75      | Distance between tape edge and hole center            |
| F              | 12.0      | Cumulative error +0.1 (max) per 10 feed holes -0.3    |
| G              | 4.0       | Cumulative error +0.1 (max) per 10 feed holes         |
| K <sub>0</sub> | 2.4       | Internal space  |

#### 3.6 Reel

- (1) Material: Plastic
- (2) Dimensions: The reel dimensions are as shown in Figure 3 and Table 3.



Unit: mm Symbol Dimension Α  $\Phi$ 330 ± 2 В Φ100 ± 1 С  $\Phi$ 13 ± 0.5 Ε  $2.0 \pm 0.5$ U  $4.0 \pm 0.5$ 17.4 ± 1.0 W1 W2 21.4 ± 1.0

Table 3 Reel Dimension

Figure 3 Reel Forms

#### 4. Packing

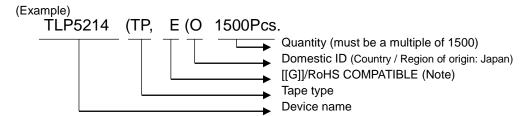
Either one reel or ten reels of photocoupler are packed in a shipping carton.

#### 5. Label Indication

The carton bears a label indicating the product number, the symbol representing classification of standard, the quantity, the lot number and Toshiba company name.

#### 6. Ordering Method

When placing an order, please specify the product number, the CTR rank, the tape and the quantity as shown in the following example.

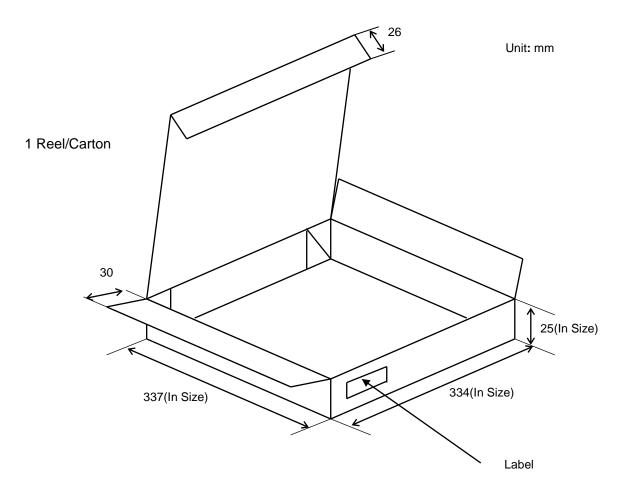


Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

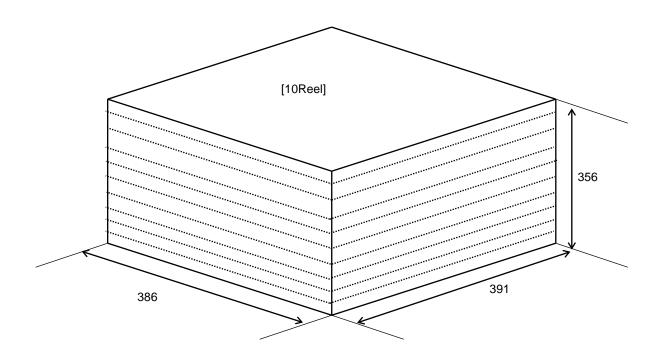
17

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

## 7. Packing Dimensions ( $\phi$ 330 mm)

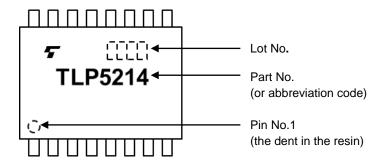


10Reel/Carton



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## 8. Marking



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